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# **Supporting Information**

Urea-Assisted Synthesis of Carbon-Doped BiNbO<sub>4</sub> with Oxygen Vacancies and Visible Light Photocatalytic Applications

Andrei Lebedev,<sup>a</sup> P. Vishakha T. Weerasinghe, +<sup>a</sup> Franklin Anariba,<sup>ab</sup> Xu Li,<sup>cd</sup> Debbie Seng Hwee Leng,<sup>c</sup> and Ping Wu<sup>\*a</sup>

- \* Correspondence: <a href="mailto:wuping@sutd.edu.sg">wuping@sutd.edu.sg</a> (Ping Wu)
- <sup>a</sup> Entropic Interface Group, Engineering Product Development, Singapore University of Technology and Design, Singapore; <u>andrei\_lebedev@alumni.sutd.edu.sg</u>; <u>puwakdandawe@mymail.sutd.edu.sg</u>.
- <sup>b</sup> Anariba Brands Group, Science, Mathematics and Technology, affiliated to Engineering Product Development, Singapore University of Technology and Design, Singapore; <u>franklin\_anariba@sutd.edu.sg</u>.

<sup>c</sup> Institute of Materials Research and Engineering, Agency for Science, Technology and Research (A\*STAR), Singapore; <u>x-li@imre.a-star.edu.sg</u>; <u>debbie-seng@imre.a-star.edu.sg</u>.

<sup>d</sup> Institute of Sustainability for Chemicals, Energy and Environment, Agency for Science, Technology and Research (A\*STAR), Singapore, Singapore; <u>x-li@imre.a-star.edu.sg</u>.

## SI1. Micro-Raman spectra of BiNbO<sub>4</sub> and U-BiNbO<sub>4</sub>.



**Figure S1**. Raman spectra in the (a) 100 - 250 cm-1 and (b) 550 - 900 cm-1 regions for pristine BiNbO<sub>4</sub> and U-BiNbO<sub>4</sub>.





**Figure S2**. XPS spectra of Bi4f and Nb3d for pristine BiNbO<sub>4</sub> (panels A, C) and U-BiNbO<sub>4</sub> (panels B, D), respectively

The Bi4f spectrum of pristine BiNbO4 suggest the presence of Bi3+ (with main peaks at 159.2 eV and 164.5 eV, respectively), while the Bi4f spectrum of U-BiNbO<sub>4</sub> also consist of Bi(+3) only (with more predominate peaks at 159.2 eV and 164.5 eV, respectively <sup>1</sup>. The Nb3d spectrum of pristine BiNbO<sub>4</sub> also propose the presence of two chemical states of Nb(4+) (206.9 eV and 209.6 eV, respectively) and Nb(+5) (210.0 eV and 212.8 eV, respectively), while the U-BiNbO4 has only Nb(+4) on the surface<sup>2</sup>. Reduced amounts of oxygen at Bi4f and Nb3d chemical states for U-BiNbO4 catalyst is another evidence of the enhanced presence of surface oxygen vacancies. No traces of nitrogen were detected in both samples.

SI3. EDS mapping images and spectrum of  $BiNbO_4$  (panels (A) and (C)) and U-BiNbO<sub>4</sub> (panels (B) and (D)), respectively.



**Figure S3**. EDS mapping and spectral images for pristine BiNbO<sub>4</sub> (panels A and C) and U-BiNbO<sub>4</sub> (panels B and D); EDS spectra taken on Cu substrate indicated by green lines.

# SI4. CHNS (Carbon, Hydrogen, Nitrogen and Sulphur) Elemental Analysis

CHNS elemental analysis was carried out using FLASH EA 1112 Series, CHNS-O Analyzer. Furnace temp is at 950 0C, testing time is 720 sec per sample. The weight percentage of C for  $BiNbO_4$  and U- $BiNbO_4$  is 0.0385 % and 0.1077 %, respectively.

Sample	C (wt%)	H(wt%)
BiNbO4	0.0385	0.0763
U-BiNbO4	0.1077	0.0865

Table	S1.	Percentage	of	С	and	Н.
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#### SI5. Overall XPS survey spectra of U-BiNbO<sub>4</sub>



Figure S4: XPS survey spectra of U-BiNbO<sub>4</sub>

# SI6. Characteristic absorption bands of cationic A) MB and B) BG dyes for U-BiNbO<sub>4</sub> catalyst



Figure S5: Characteristic absorption bands of cationic A) MB and B) BG dyes for U-BiNbO<sub>4</sub> catalyst.

SI7. Normalized photocatalytic degradation using 10, 15, 30, and 45 mg of U-BiNbO<sub>4</sub> for A) MB and B) BG dyes.



Figure S6: Photocatalytic degradation using 10, 15, 30, and 45 mg of U-BiNbO<sub>4</sub> for A) MB and B) BG dyes.

# SI8. Normalized photocatalytic degradation of MB in different pH using U-BiNbO4



Figure S7: Photocatalytic degradation using pH 11.5,9.5,5.5 and 3.5 solutions of U-BiNbO<sub>4</sub> for MB.

## References

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- 2. K. Senevirathne, R. Hui, S. Campbell, S. Ye and J. Zhang, *Electrochimica Acta*, 2012, **59**, 538-547.